74AUP1T97 Low-power configurable gate with voltage-level translator Rev. 6 — 28 March 2017 Product data s

General description 1

The 74AUP1T97 provides low-power, low-voltage configurable logic gate functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter and buffer. All inputs can be connected to V_{CC} or GND.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 2.3 V to 3.6 V.

The 74AUP1T97 is designed for logic-level translation applications with input switching levels that accept 1.8 V low-voltage CMOS signals, while operating from either a single 2.5 V or 3.3 V supply voltage.

The wide supply voltage range ensures normal operation as battery voltage drops from 3.6 V to 2.3 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Schmitt trigger inputs make the circuit tolerant to slower input rise and fall times across the entire V_{CC} range.

Features and benefits 2

- Wide supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5 000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1 000 V
- Low static power consumption; I_{CC} = 1.5 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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Product data sheet

3 Ordering information

Table 1. Ordering	information							
Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1T97GW	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74AUP1T97GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm	SOT886				
74AUP1T97GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm	SOT891				
74AUP1T97GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm	SOT1115				
74AUP1T97GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm	SOT1202				
74AUP1T97GX	-40 °C to +125 °C	X2SON6	plastic thermal extremely thin small outline package; no leads; 6 terminals; body 1 x 0.8 x 0.35 mm	SOT1255				
74AUP1T97UK	-40 °C to +125 °C	WLCSP6	wafer level chip-scale package; 6 bumps; 0.65 x 0.44 x 0.27 mm	SOT1454-1				

4 Marking

	Table	2.	Marking
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Type number	Marking code ^[1]
74AUP1T97GW	59
74AUP1T97GM	59
74AUP1T97GF	59
74AUP1T97GN	59
74AUP1T97GS	59
74AUP1T97GX	59
74AUP1T97UK	9

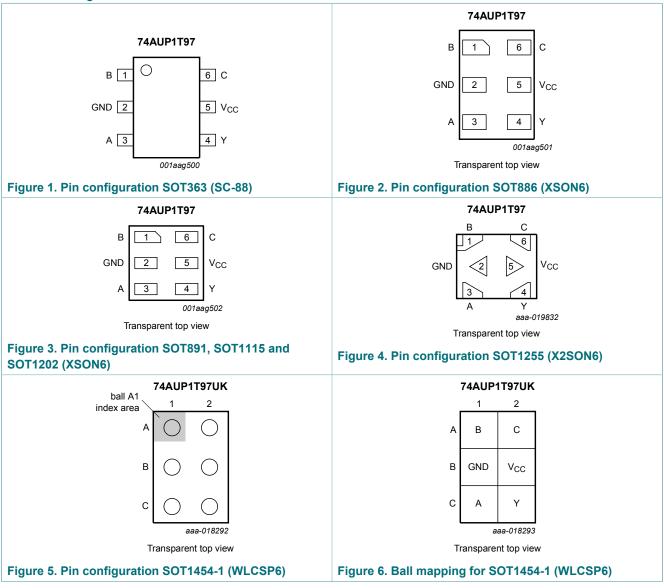
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

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5 Pinning information

5.1 Pinning





5.2 Pin description

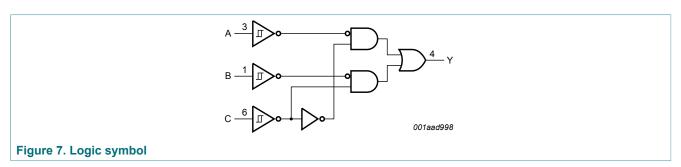
Symbol	Pin	Pin			
	SC88, XSON6 and X2SON6	WLCSP6			
В	1	A1	data input		
GND	2	B1	ground (0 V)		
A	3	C1	data input		
Y	4	C2	data output		
V _{CC}	5	B2	supply voltage		
С	6	A2	data input		

6 Functional description

Table 5. Function table ^[1]			
Input	Input		
C	В	Α	Y
L	L	L	L
L	L	Н	L
L	Н	L	Н
L	Н	Н	Н
Н	L	L	L
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	Н

[1] H = HIGH voltage level; L = LOW voltage level.

7 Functional diagram



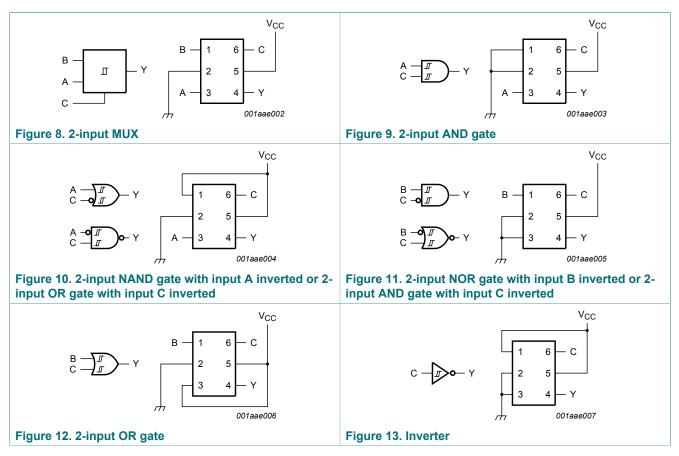
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8 Logic configurations

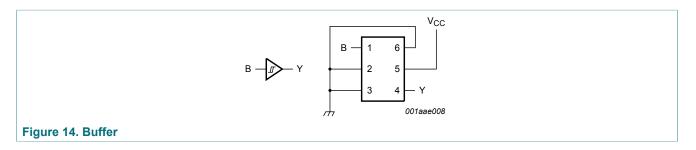
Table 6. Function selection table

Logic function	Figure
2-input MUX	see Figure 8
2-input AND	see Figure 9
2-input OR with one input inverted	see Figure 10
2-input NAND with one input inverted	see Figure 10
2-input AND with one input inverted	see Figure 11
2-input NOR with one input inverted	see Figure 11
2-input OR	see Figure 12
Inverter	see Figure 13
Buffer	see Figure 14



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9 Limiting values

Table 7. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _O	output current	V_{O} = 0 V to V_{CC}		-	±20	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 package: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

For X2SON6 and XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

For WLCSP6 package: above 102.5 $^\circ\text{C}$ the value of P_tot derates linearly with 5.3 mW/K.

10 Recommended operating conditions

Table 8. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V_{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

11 Static characteristics

Table 9. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Uni
T _{amb} = 25	5 °C					
V _{T+}	positive-going	V_{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	threshold voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.16	V
V _{T-}	negative-going	V_{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
	threshold voltage	V _{CC} = 3.0 V to 3.6 V	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_{H} = V_{T^{+}} - V_{T^{-}})$				
		V_{CC} = 2.3 V to 2.7 V	0.23	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.25	-	1.10 1.16 0.60 0.85	V
V _{он}	HIGH-level output	$V_{I} = V_{T+} \text{ or } V_{T-}$			 1.10 1.16 0.60 0.85 0.60 0.56 - - - - - - - 0.10 0.31 0.44 0.31 0.44 ±0.1 ±0.1 ±0.1 ±0.1 ±0.2 1.2 - - - 1.10 	
	voltage	I_{O} = -20 µA; V_{CC} = 2.3 V to 3.6 V	V _{CC} - 0.1	-		V
		$I_{\rm O}$ = -2.3 mA; $V_{\rm CC}$ = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
	I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V	
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 2.3 V to 3.6 V	-	-	0.10	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-		0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	 1.10 1.16 0.60 0.85 0.60 0.85 0.60 0.56 0.56 - - - - 0.10 0.31 0.44 0.31 0.44 1.10 	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-		V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-		V
I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.1	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
lcc	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 2.3 V to 3.6 V	-	-	1.2	μA
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.8	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF
T _{amb} = -4	0 °C to +85 °C					
V _{T+}	positive-going	V _{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	threshold voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.19	V

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{T-}	negative-going	V _{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
	threshold voltage	V _{CC} = 3.0 V to 3.6 V	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_{H} = V_{T^{+}} - V_{T^{-}})$				
		V _{CC} = 2.3 V to 2.7 V	0.10	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.15	-	0.56	V
V _{OH}	HIGH-level output	$V_{I} = V_{T+}$ or V_{T-}				
	voltage	$I_{\rm O}$ = -20 µA; V _{CC} = 2.3 V to 3.6 V	V _{CC} - 0.1	-	-	V
		$I_{\rm O}$ = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		$I_{\rm O}$ = -2.7 mA; $V_{\rm CC}$ = 3.0 V	2.67	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{T+}$ or V_{T-}				
	voltage	I_{O} = 20 µA; V_{CC} = 2.3 V to 3.6 V	-	-	0.85 0.60 0.56 - -	V
		$I_{\rm O}$ = 2.3 mA; $V_{\rm CC}$ = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		$I_{\rm O}$ = 2.7 mA; $V_{\rm CC}$ = 3.0 V	-	-	0.85 0.60 0.56 - - - 0.1 0.33 0.45 0.33 0.45 ±0.5 ±0.5 ±0.5 ±0.5 ±0.5 1.5 4 1.2 1.10 1.19 0.64 0.85	V
		$I_{\rm O}$ = 4.0 mA; $V_{\rm CC}$ = 3.0 V	-	-	0.45	V
lı	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.5	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	1.5	μA
ΔI _{CC}	additional supply	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$ [1]	-	-	4	μA
	current	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}; \text{ I}_{O} = 0 \text{ A}$ [2]	-	-	12	μA
$T_{amb} = -40$	0 °C to +125 °C				1	
V _{T+}	positive-going	V _{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	threshold voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.19	V
V _{T-}	negative-going	V _{CC} = 2.3 V to 2.7 V	0.33	-	0.64	V
	threshold voltage	V _{CC} = 3.0 V to 3.6 V	0.46	-	0.85	V
V _H	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				
		V _{CC} = 2.3 V to 2.7 V	0.10	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.15	-	0.56	V
V _{OH}	HIGH-level output	$V_{I} = V_{T+}$ or V_{T-}				
	voltage	I_{O} = -20 µA; V_{CC} = 2.3 V to 3.6 V	V _{CC} - 0.11	-	-	V

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
		$I_{\rm O}$ = -2.3 mA; $V_{\rm CC}$ = 2.3 V	1.77	-	-	V
		$I_{\rm O}$ = -3.1 mA; $V_{\rm CC}$ = 2.3 V	1.67	-	-	V
		$I_{\rm O}$ = -2.7 mA; $V_{\rm CC}$ = 3.0 V	2.40	-	-	V
		$I_{\rm O}$ = -4.0 mA; $V_{\rm CC}$ = 3.0 V	2.30	-	-	V
I _I ii I _{OFF} F	LOW-level output	$V_{I} = V_{T+}$ or V_{T-}				
	voltage	I_{O} = 20 µA; V_{CC} = 2.3 V to 3.6 V	-	-	0.11	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	$\begin{array}{c} 0.36 \\ 0.50 \\ 0.36 \\ 0.50 \\ \pm 0.75 \\ \pm 0.75 \\ \pm 0.75 \\ \pm 0.75 \\ 3.5 \end{array}$	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-		V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-		V
I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
Δl _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	3.5	μA
ΔI _{CC}	additional supply	V_{CC} = 2.3 V to 2.7 V; I _O = 0 A	[1] _	-	7	μA
	current	V_{CC} = 3.0 V to 3.6 V; I _O = 0 A	[2] _	-	22	μA

One input at 0.3 V or 1.1 V, other input at V_{CC} or GND. One input at 0.45 V or 1.2 V, other input at V_{CC} or GND. [1] [2]

12 Dynamic characteristics

Table 10. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 16.

Symbo	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
V _{CC} = 2	.3 V to 2.7 V; V _I = 1.65	V to 1.95 V			1			1	_
t _{pd}	propagation delay	A, B, C to Y; see <u>Figure 15</u> ^[2]							
		C _L = 5 pF	2.2	3.5	5.5	0.5	6.8	7.5	ns
		C _L = 10 pF	2.6	4.1	6.3	1.0	7.9	8.7	ns
		C _L = 15 pF	2.9	4.6	6.9	1.0	8.7	9.6	ns
		C _L = 30 pF	3.7	5.8	8.4	1.5	10.8	11.9	ns
V _{CC} = 2	.3 V to 2.7 V; $V_1 = 2.3$ V	/ to 2.7 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 15 ^[2]							
		C _L = 5 pF	1.8	3.4	5.5	0.5	6.0	6.6	ns
		C _L = 10 pF	2.2	4.0	6.2	1.0	7.1	7.9	ns
		C _L = 15 pF	2.5	4.4	6.8	1.0	7.9	8.7	ns
		C _L = 30 pF	3.2	5.6	8.3	1.5	10.0	11.0	ns
V _{CC} = 2	.3 V to 2.7 V; $V_1 = 3.0$ V	/ to 3.6 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 15 ^[2]							
		C _L = 5 pF	1.4	3.1	5.0	0.5	5.5	6.1	ns
		C _L = 10 pF	1.8	3.7	5.7	1.0	6.5	7.2	ns
		C _L = 15 pF	2.2	4.2	6.3	1.0	7.4	8.2	ns
		C _L = 30 pF	2.9	5.3	7.9	1.5	9.5	10.5	ns
V _{CC} = 3	.0 V to 3.6 V; V _I = 1.65	V to 1.95 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 15 ^[2]							
		C _L = 5 pF	2.1	2.9	3.9	0.5	8.0	8.8	ns
		C _L = 10 pF	2.5	3.4	4.6	1.0	8.5	9.4	ns
		C _L = 15 pF	2.9	3.9	5.2	1.0	9.1	10.1	ns
		C _L = 30 pF	3.6	5.0	6.7	1.5	9.8	10.8	ns
V _{CC} = 3	.0 V to 3.6 V; $V_1 = 2.3$ V	/ to 2.7 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 15 ^[2]							
		C _L = 5 pF	1.7	2.8	4.2	0.5	5.3	5.9	ns
		C _L = 10 pF	2.1	3.4	5.0	1.0	6.1	6.8	ns
		C _L = 15 pF	2.4	3.8	5.6	1.0	6.8	7.5	ns
		C _L = 30 pF	3.2	5.0	7.1	1.5	8.5	9.4	ns
V _{CC} = 3	.0 V to 3.6 V; $V_1 = 3.0$ V	/ to 3.6 V							,
t _{pd}	propagation delay	A, B, C to Y; see Figure 15 ^[2]							
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Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
		C _L = 5 pF	1.4	2.7	4.2	0.5	4.7	5.2	ns
		C _L = 10 pF	1.8	3.3	5.0	1.0	5.7	6.3	ns
		C _L = 15 pF	2.1	3.8	5.6	1.0	6.2	6.9	ns
		C _L = 30 pF	2.9	4.9	7.1	1.5	7.8	8.6	ns
T _{amb} = 25 °C									
C _{PD}	power dissipation capacitance	f_i = 1 MHz; V_I = GND to V_{CC} ^[3]							
		V _{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.3	-	-	-	-	pF

All typical values are measured at nominal $\ensuremath{\mathsf{V}_{\text{CC}}}$ [1]

[2] [3]

 t_{pd} is the same as t_{PLH} and t_{PHL} C_{PD} is used to determine the dynamic power dissipation (P_D in µW).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

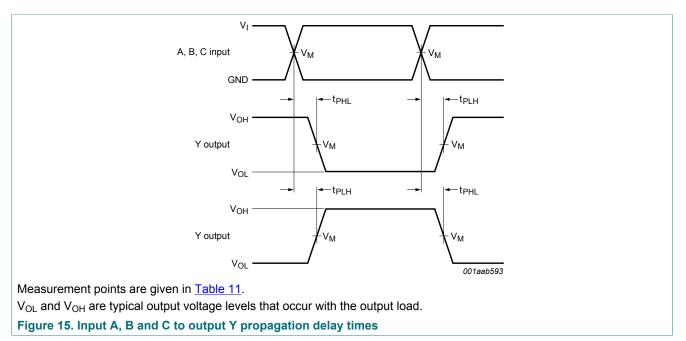
fo = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1 Waveforms and test circuit

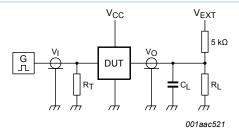


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Table 11. Measurement points

Supply voltage	Output	Input		
V _{cc}	V _M	V _M	VI	$\mathbf{t}_{r} = \mathbf{t}_{f}$
2.3 V to 3.6 V	0.5V _{CC}	0.5V _l	1.65 V to 3.6 V	≤ 3.0 ns



Test data is given in Table 12.

Definitions test circuit:

 R_T = termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = load capacitance including jig and probe capacitance.

R_L = load resistance.

Figure 16. Test circuit for measuring switching times

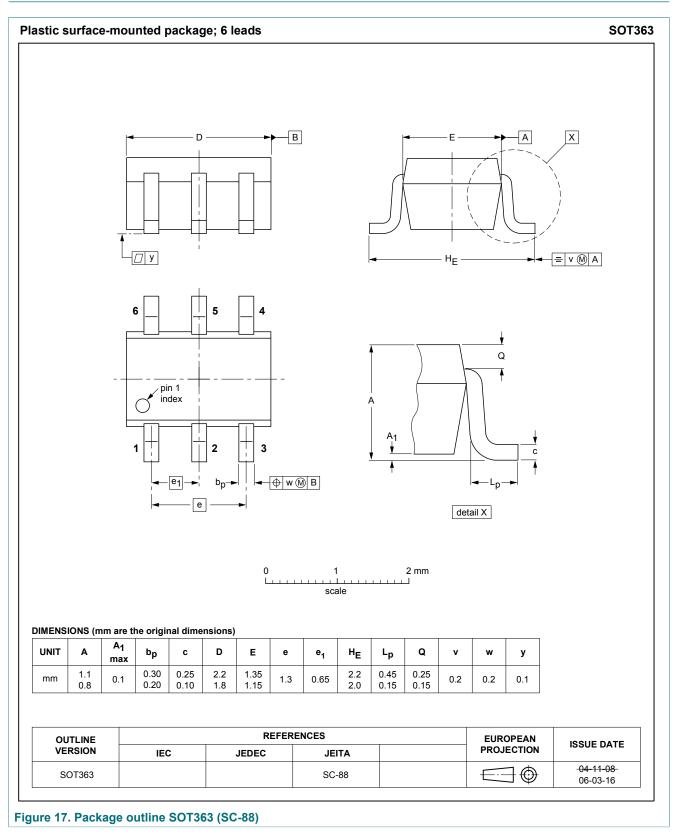
Table 12. Test data

Supply voltage	Load		V _{EXT}			
V _{cc}	CL	R _L ^[1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
2.3 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	2 × V _{CC}	

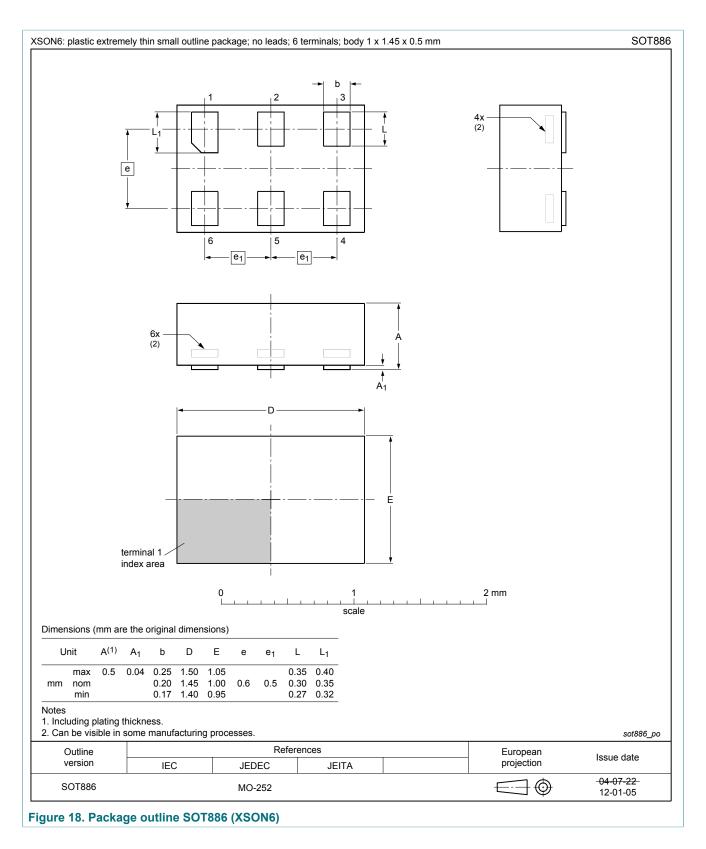
[1] For measuring enable and disable times $R_L = 5 k\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 M\Omega$.

Low-power configurable gate with voltage-level translator

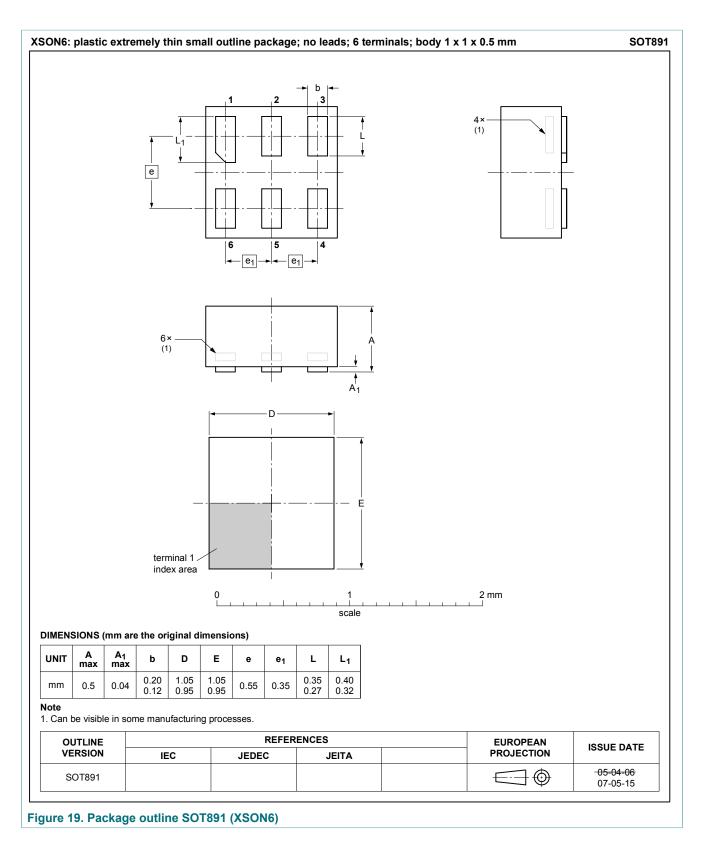
13 Package outline



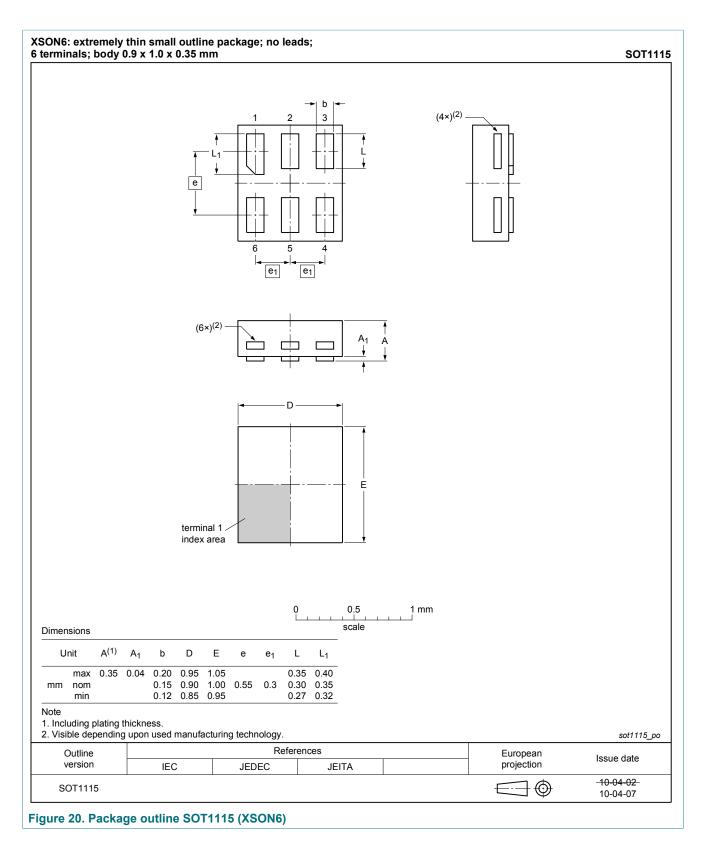
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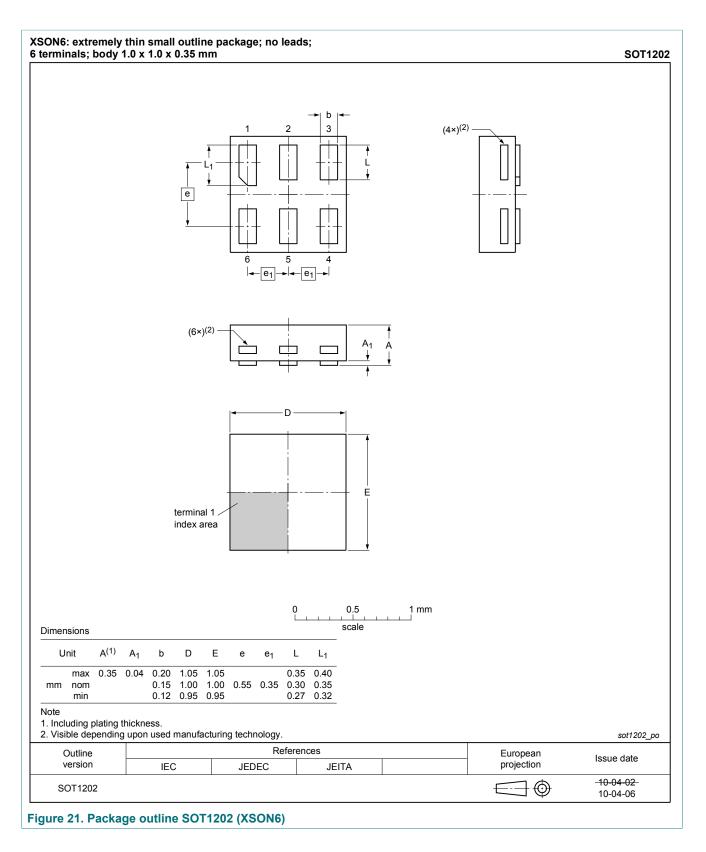
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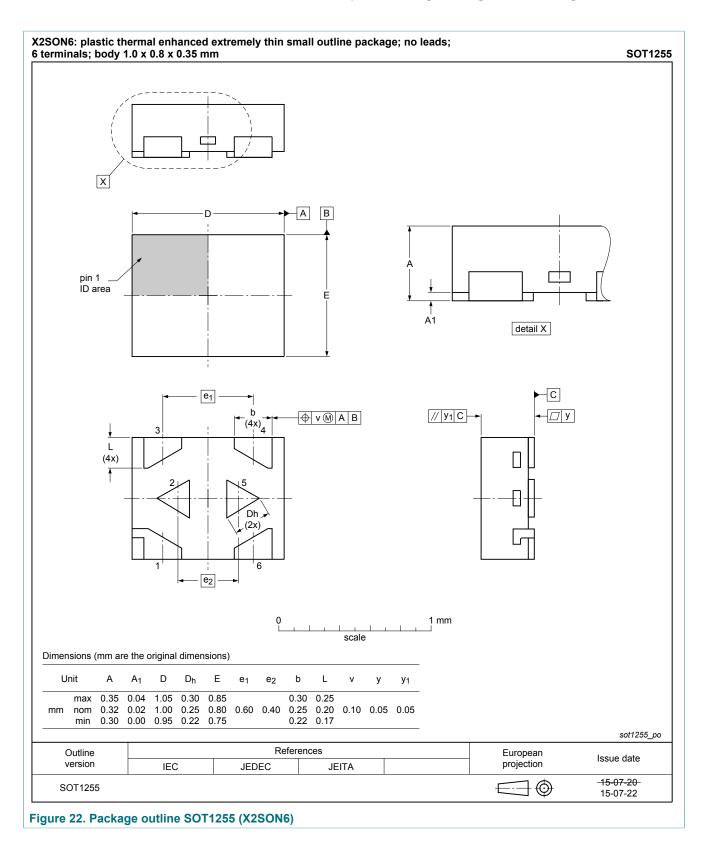
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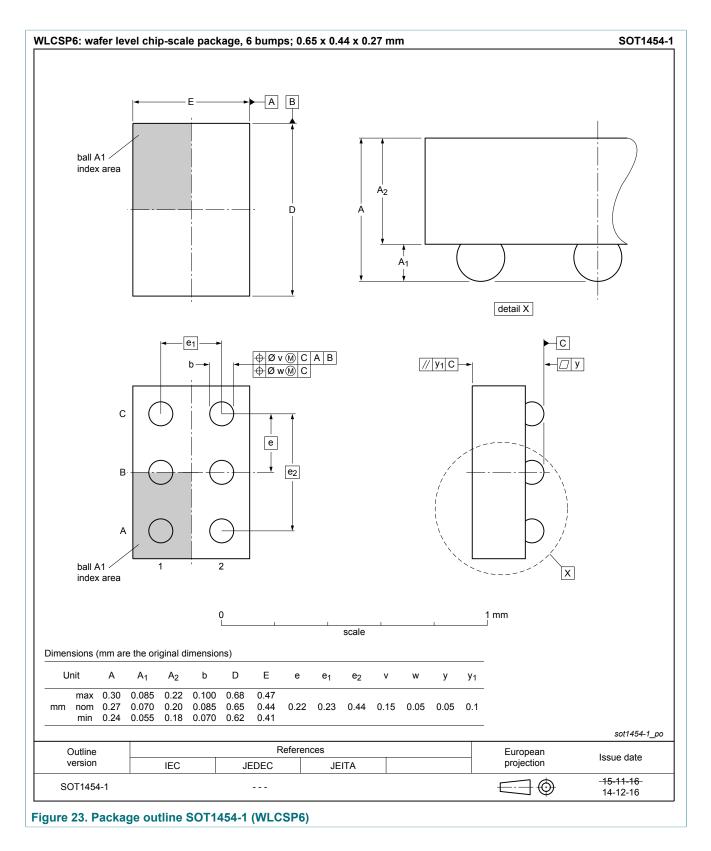


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14 Abbreviations

Table 13. Abbreviations				
Description				
Charged Device Model				
Complementary Metal Oxide Semiconductor				
Device Under Test				
ElectroStatic Discharge				
Human Body Model				
Machine Model				

15 Revision history

Table 14. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP1T97 v.6	20170328	Product data sheet	-	74AUP1T97 v.5		
Modifications:	Added type number 74AUP1T97UK (WLCSP6).					
74AUP1T97 v.5	20150917	Product data sheet	-	74AUP1T97 v.4		
Modifications:	Added type number 74AUP1T97GX (SOT1255/X2SON6).					
74AUP1T97 v.4	20120815	Product data sheet	-	74AUP1T97 v.3		
Modifications:	 Package outline drawing of SOT886 (Figure 18) modified. 					
74AUP1T97 v.3	20111130	Product data sheet	-	74AUP1T97 v.2		
74AUP1T97 v.2	20101018	Product data sheet	-	74AUP1T97 v.1		
74AUP1T97 v.1	20071025	Product data sheet	-	-		

16 Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions". [2] [3]

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